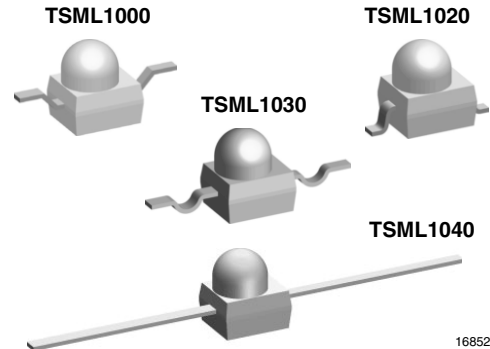


High Power Infrared Emitting Diode, 950 nm, GaAlAs/GaAs

Description

TSML1000 series are high efficiency infrared emitting diodes in GaAlAs on GaAs technology molded in clear SMD package.

This technology represents best performance for radiant power under pulse conditions, forward voltage and reliability.



Features

- Outstanding high radiant power
- Low forward voltage
- Suitable for high pulse current operation
- Angle of half intensity $\varphi = \pm 12^\circ$
- Peak wavelength $\lambda_p = 950 \text{ nm}$
- High reliability
- Matched Phototransistor series: TEMT1000
- Versatile terminal configurations
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



Applications

- For remote control
- Photointerrupters
- Punched tape readers
- Encoder

Absolute Maximum Ratings

$T_{amb} = 25^\circ\text{C}$, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Reverse voltage		V_R	5	V
Forward current		I_F	100	mA
Peak forward current	$t_p/T = 0.5, t_p = 100 \mu\text{s}$	I_{FM}	200	mA
Surge forward current	$t_p = 100 \mu\text{s}$	I_{FSM}	1.0	A
Power dissipation		P_V	190	mW
Junction temperature		T_j	100	$^\circ\text{C}$
Operating temperature range		T_{amb}	- 40 to + 85	$^\circ\text{C}$
Storage temperature range		T_{stg}	- 40 to + 100	$^\circ\text{C}$
Soldering temperature	$t \leq 5 \text{ sec}$	T_{sd}	< 260	$^\circ\text{C}$
Thermal resistance junction/ambient		R_{thJA}	400	$^\circ\text{C}$

Basic Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Forward voltage	$I_F = 20\text{ mA}$, $t_p = 20\text{ ms}$	V_F		1.2	1.5	V
	$I_F = 1\text{ A}$, $t_p = 100\text{ }\mu\text{s}$	V_F		2.6		V
Temp. coefficient of V_F	$I_F = 1\text{ mA}$	TK_{V_F}		- 1.85		mV/K
Reverse current	$V_R = 5\text{ V}$	I_R			10	μA
Junction capacitance	$V_R = 0\text{ V}$, $f = 1\text{ MHz}$, $E = 0$	C_j		25		pF
Radiant intensity	$I_F = 20\text{ mA}$, $t_p = 20\text{ ms}$	I_e	3	7	15	mW/sr
Radiant power	$I_F = 100\text{ mA}$, $t_p = 20\text{ ms}$	ϕ_e		35		mW
Temp. coefficient of ϕ_e	$I_F = 20\text{ mA}$	TK_{ϕ_e}		- 0.6		%/K
Angle of half intensity		φ		± 12		deg
Peak wavelength	$I_F = 100\text{ mA}$	λ_p		950		nm
Spectral bandwidth	$I_F = 100\text{ mA}$	$\Delta\lambda$		50		nm
Temp. coefficient of λ_p	$I_F = 100\text{ mA}$	TK_{λ_p}		0.2		nm/K
Rise time	$I_F = 100\text{ mA}$	t_r		800		ns
Fall time	$I_F = 100\text{ mA}$	t_f		800		ns
Virtual source diameter		\varnothing		1.2		mm

Typical Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

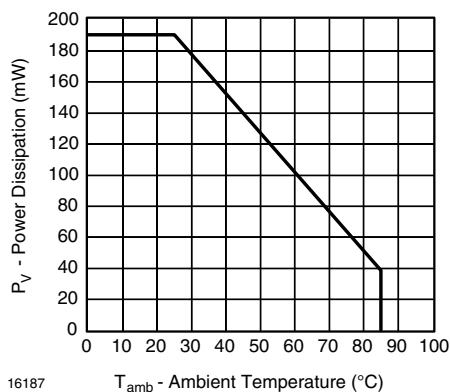


Figure 1. Power Dissipation vs. Ambient Temperature

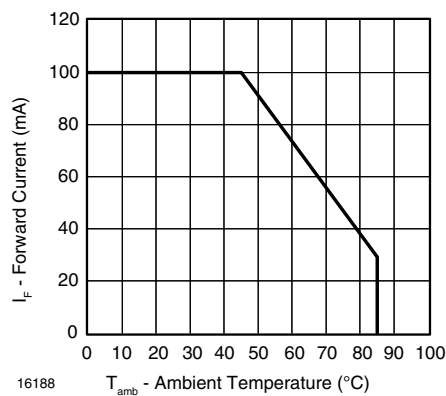


Figure 2. Forward Current vs. Ambient Temperature

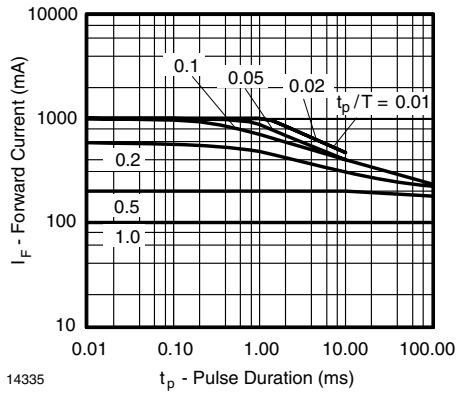


Figure 3. Pulse Forward Current vs. Pulse Duration

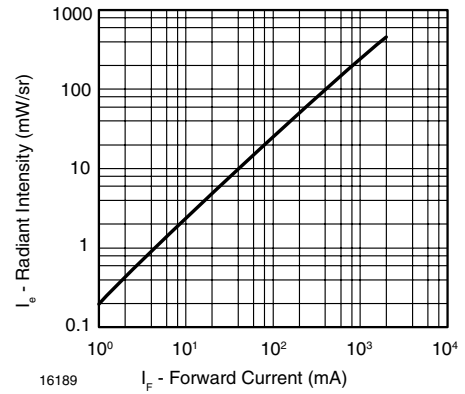


Figure 6. Radiant Intensity vs. Forward Current

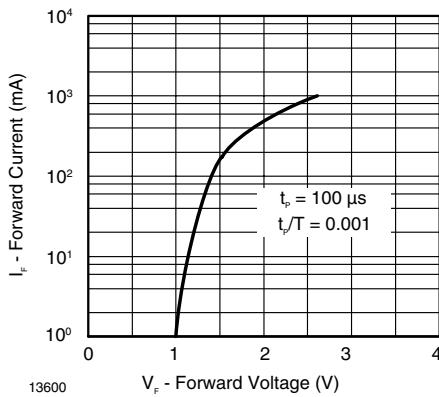


Figure 4. Forward Current vs. Forward Voltage

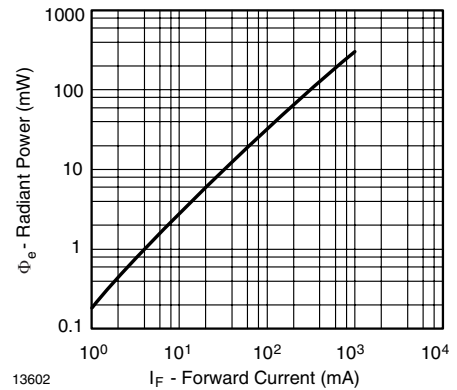


Figure 7. Radiant Power vs. Forward Current

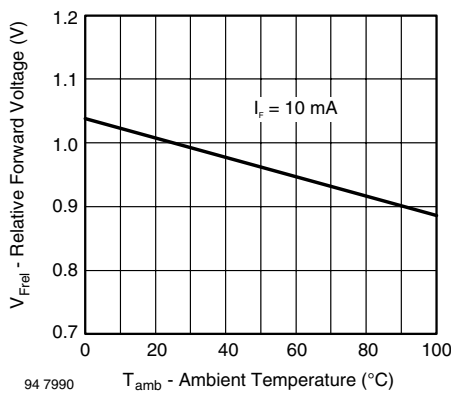


Figure 5. Relative Forward Voltage vs. Ambient Temperature

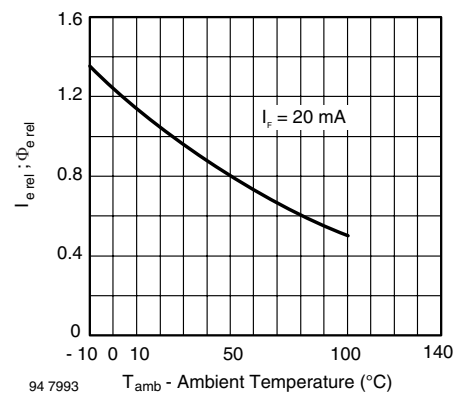


Figure 8. Rel. Radiant Intensity/Power vs. Ambient Temperature

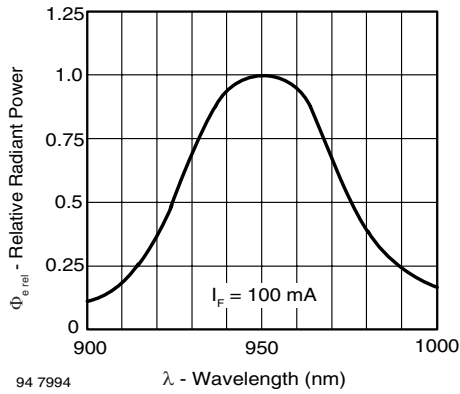


Figure 9. Relative Radiant Power vs. Wavelength

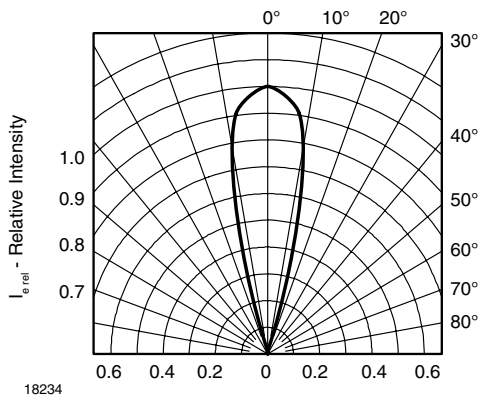
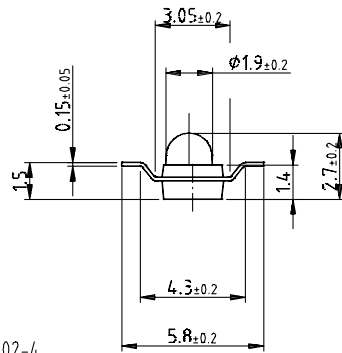


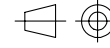
Figure 10. Relative Radiant Intensity vs. Angular Displacement



Package Dimensions in mm TSML1000



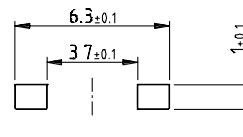
Drawing-No.: 6.544-5326.02-4
Issue: 3; 02.04.03



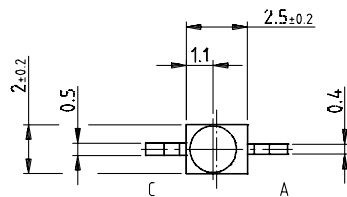
technical drawings
according to DIN
specifications

All dimensions in mm

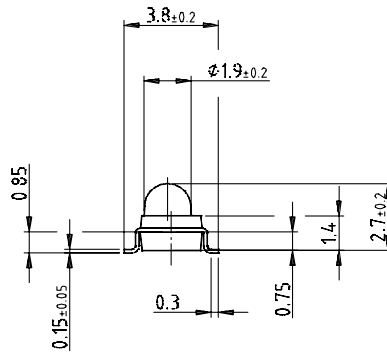
Solder pad proposal



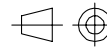
16159



Package Dimensions in mm TSML1020



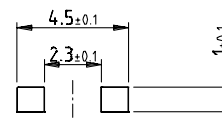
Drawing-No.: 6.544-5325.02-4
Issue: 3; 02.04.03



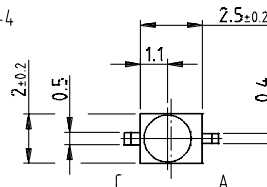
technical drawings
according to DIN
specifications

All dimensions in mm

Solder pad proposal



16160

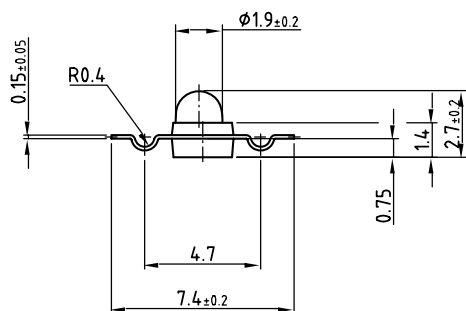


TSML1000/1020/1030/1040



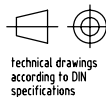
Vishay Semiconductors

Package Dimensions in mm
TSML1030



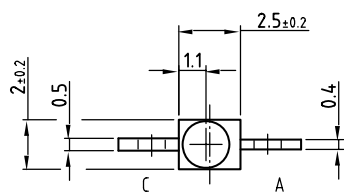
Drawing-No.: 6.544-5329.01-4

Issue: 4; 08.05.03

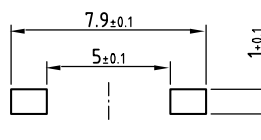


Technical drawings according to DIN specifications

All dimensions in mm

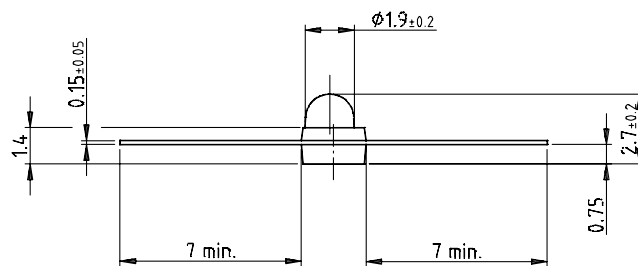


Solder pad proposal



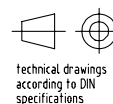
16228

Package Dimensions in mm
TSML1040



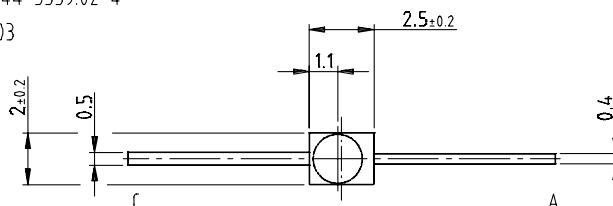
Drawing-No.: 6.544-5339.02-4

Issue: 3; 02.04.03



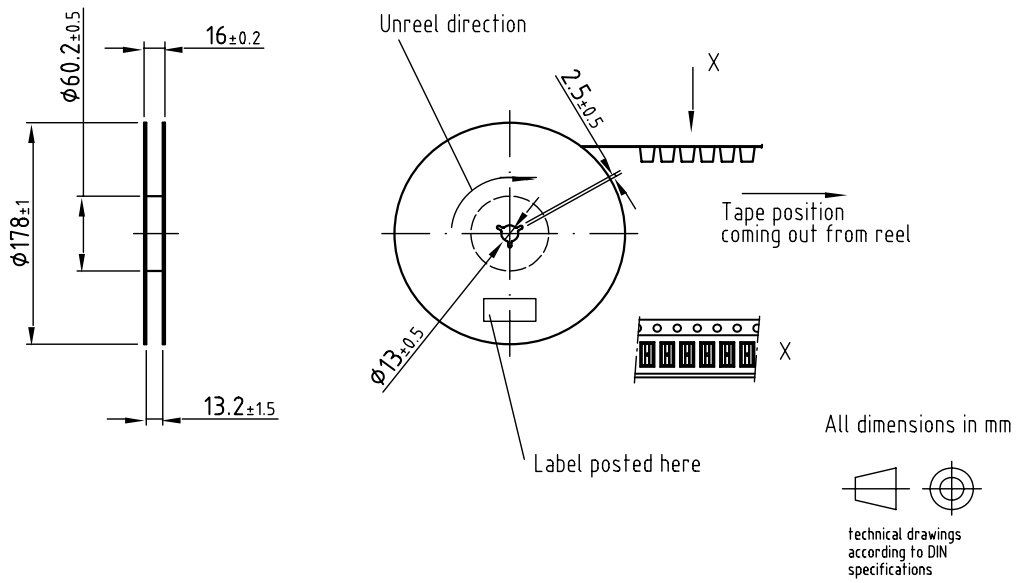
Technical drawings according to DIN specifications

All dimensions in mm

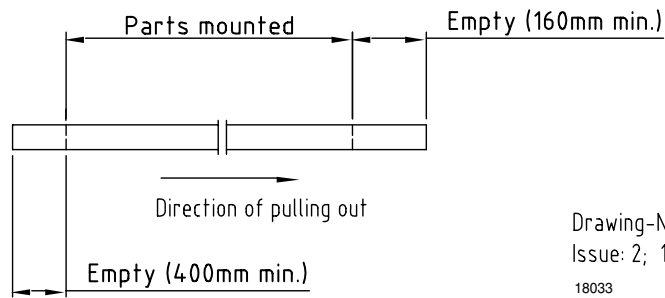


16760

Reel Dimensions



Leader and trailer tape:



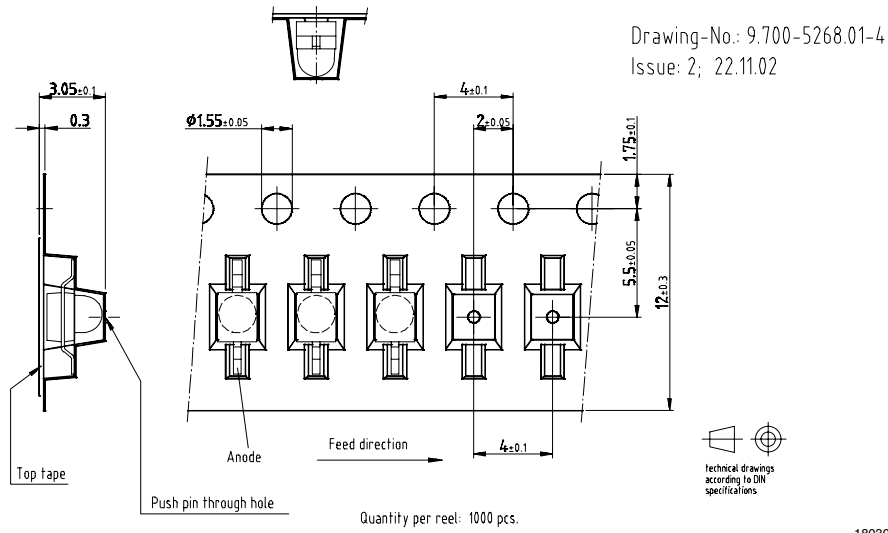
Drawing-No.: 9.800-5080.01-4
 Issue: 2; 18.11.02
 18033

TSML1000/1020/1030/1040

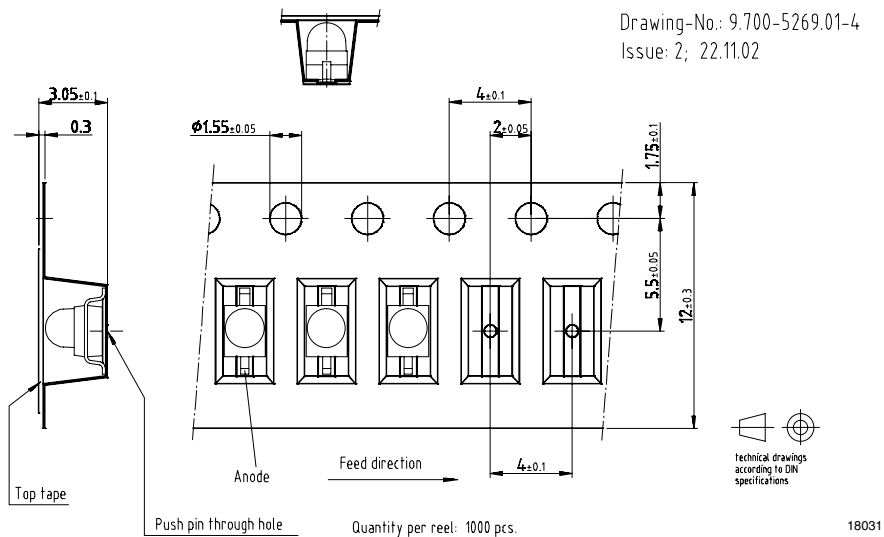
Vishay Semiconductors



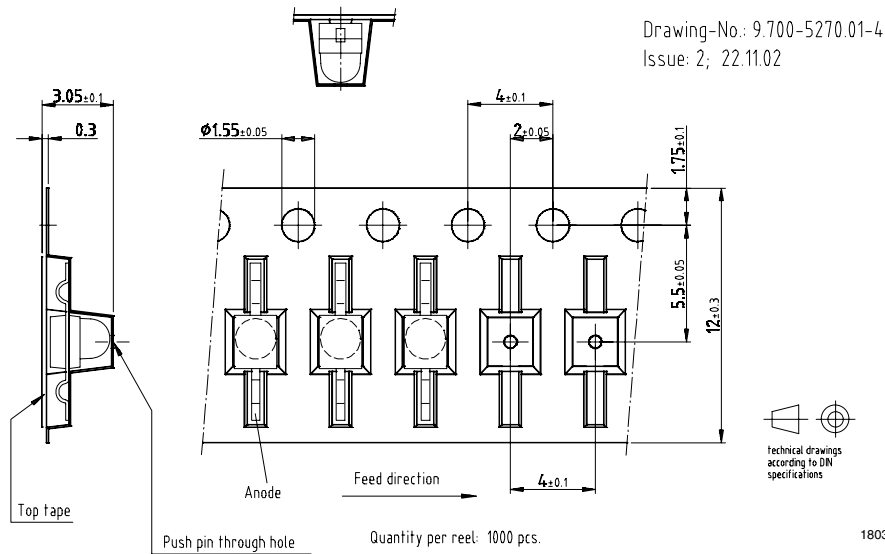
Taping TSML1000



Taping TSML1020



Taping TSML1030



Precautions For Use

1. Over-current-proof

Customer must apply resistors for protection, otherwise slight voltage shift will cause big current change (Burn out will happen).

2. Storage

2.1 Storage temperature and rel. humidity conditions are: $5\text{ }^{\circ}\text{C}$ to $35\text{ }^{\circ}\text{C}$, R.H. 60 %.

2.2 Floor life must not exceed 168 h, acc. to JEDEC level 3, J-STD-020.

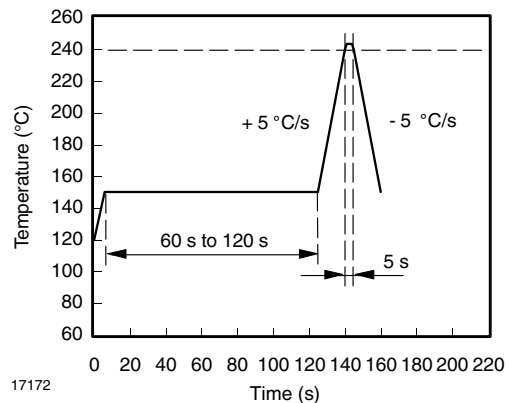
Once the package is opened, the products should be used within a week. Otherwise, they should be kept in a damp proof box with desiccant.

Considering tape life, we suggest to use products within one year from production date.

2.3 If opened more than one week in an atmosphere $5\text{ }^{\circ}\text{C}$ to $35\text{ }^{\circ}\text{C}$, R.H. 60 %, devices should be treated at $60\text{ }^{\circ}\text{C} \pm 5\text{ }^{\circ}\text{C}$ for 15 hrs.

2.4 If humidity indicator in the package shows pink color (normal blue), then devices should be treated with the same conditions as 2.3.

Reflow Solder Profile



Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design
and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[Vishay:](#)

[TSML1020](#)